

3-Channel Low Dropout RGB LED Driver

General Description

The RT9301 is a 3-Channel current source driver for RGB LED. It is easy to be designed in applications that need mixing RGB light source for multi-color output.

The RT9301 also provide users with great flexibility and device performance. It uses externals resistor to set the bias current for three LEDs, which are matched to 5%(max.). Users can adjust the output current from 2mA to 50mA by setting the ISET resistor.

The RT9301 features very low dropout and under voltage lockout protection. It is available in a space-saving TSOT-23-8 and WDFN-8L 3x3 packages.

Ordering Information

Package Type

J8: TSOT-23-8

QW: WDFN-8L 3x3 (Green Only)

Lead Plating System

P: Pb Free

G: Green (Halogen Free and Pb Free)

Note:

- WDFN-8L 3x3 is in W-Type
- Richtek products are :
 - RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
 - ▶ Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

For marking information, contact our sales representative directly or through a Richtek distributor located in your area.

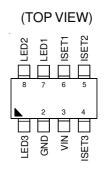
Features

- Input Voltage Range: 2.8V to 5.5V
- Low 60/45mV Dropout at 20/15mA
- Individual Current Setting by External Resistor
- Individual On/Off Control by Baseband MPU
- Up to 50mA LED Bias Current
- Simple LED Brightness Control
- 5%(max.) LED Current Matching
- Low 0.1uA Shutdown Current
- UVLO Protection
- RoHS Compliant and 100% Lead (Pb)-Free

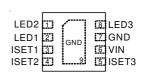
Applications

- Mobile phone, Smart Phone Multi-color LED Backlight
- Camera Flash White LED
- LCD Display Modules
- Keypad Backlight

Pin Configurations



TSOT-23-8



WDFN-8L 3x3

Typical Application Circuit

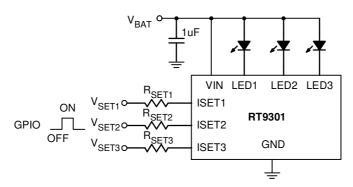


Figure 1. Application circuit for RGB LED

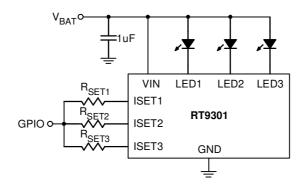


Figure 2. Application Circuit for Backlight

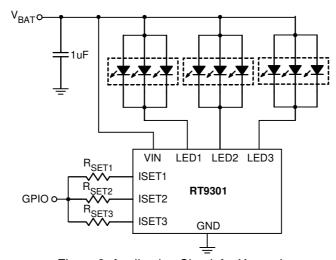


Figure 3. Application Circuit for Keypad

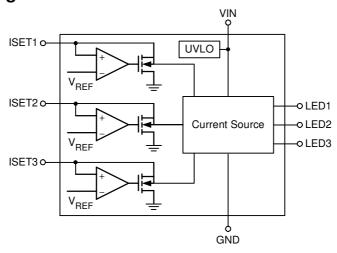
| ILED1 ~ 3 = 800 x | ISET1 ~ 3 = 800 x
$$\frac{V_{SET1} ~ 3 - 0.9V}{R_{SET1} ~ 3}$$

GPIO (V)	I _{LED} (mA)	R_{SET} (k Ω)	Nearest Standard Values for R_{SET} (k Ω)
1.8	15	48	47.5
1.0	20	36	36
2.8	15	101	100
2.0	20	76	75

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Function Block Diagram



Functional Pin Description

Pin No.		Din Nome	Pin Function	
RT9301□J8	RT9301GQW	Pin Name	Fill Fullction	
1	8	LED3	RGB or White LED cathode connection pin. 2mA to 50mA Current flows into LED. Floating or connection to ground is used to disable this pin.	
2	7, Exposed Pad (9)	GND	Ground Pin. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.	
3	6	VIN	Power Input Pin.	
4	5	ISET3	Current setting for LED3. Connect to GND if not use.	
5	4	ISET2	Current setting for LED2. Connect to GND if not use.	
6	3	ISET1	Current setting for LED1. Connect to GND if not use.	
7	2	LED1	RGB or White LED cathode connection pin. 2mA to 50mA Current flows into LED. Floating or connection to ground is used to disable this pin.	
8	1	LED2	RGB or White LED cathode connection pin. 2mA to 50mA Current flows into LED. Floating or connection to ground is used to disable this pin.	



Absolute Maximum Ratings (Note 1)

Supply Input Voltage	
LED1,2,3 Pin Voltage	
Other I/O Pin Voltages	
Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
TSOT-23-8	0.382W
WDFN-8L 3x3	0.926W
Package Thermal Resistance (Note 2)	
TSOT-23-8, θ _{JA}	262°C/W
WDFN-8L 3x3, θ_{JA}	108°C/W
WDFN-8L 3x3, θ_{JC}	8.2°C/W
Lead Temperature (Soldering, 10 sec.)	260°C
Junction Temperature	150°C
Storage Temperature Range	
ESD Susceptibility (Note 3)	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	200V
Recommended Operating Conditions (Note 4)	
Junction Temperature Range	

Electrical Characteristics

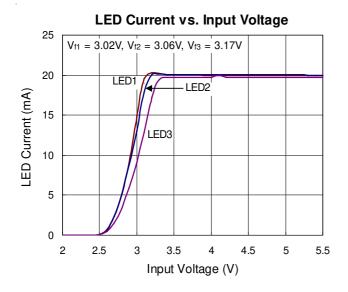
 $(V_{IN} = 3.6V, T_A = 25^{\circ}C, Unless Otherwise specification)$

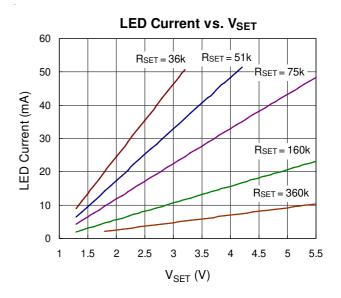
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Input Supply Voltage	V_{IN}		2.8		5.5	V
UVLO Threshold	V _{UVLO_L}	Falling	2	2.2	2.4	V
UVLO Hysteresis				100		mV
Dropout Voltage	V_{LED}	90% of I _{LED} = 16mA		40	120	mV
ISET Reference Voltage			0.8	0.9	1	٧
Quiescent Current	I_Q	LED Open, I _{SET} = 20 uA		0.5	1	mA
I _{LED} Matching		I _{LED} = 16mA	-5		+5	%
I _{LED} Accuracy	I _{LED}	I _{LED} = 16mA	-5		+5	%
Shutdown current		All V _{SET1~3} < 0.25V		0.1	2	μΑ
V _{SET} Enable Threshold	V _{SET}	V_{SET} connect $R_{SET} = 47k\Omega$ to I_{SET}	1.3			V
V _{SET} Disable Threshold	V_{IL}	V_{SET} connect $R_{SET} = 47k\Omega$ to I_{SET}			0.25	V

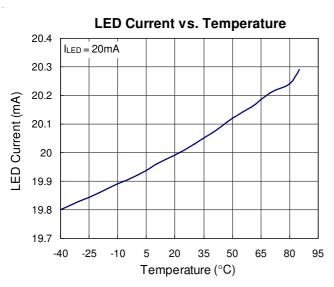
- **Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2. θ_{JA} is measured in the natural convection at $T_A = 25^{\circ}C$ on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. The case point of θ_{JC} is on the expose pad for the WDFN package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

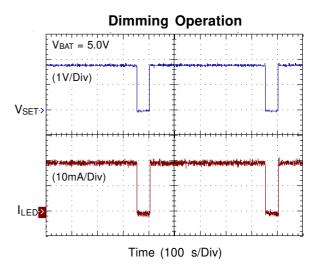


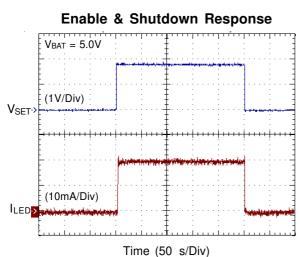
Typical Operating Characteristics

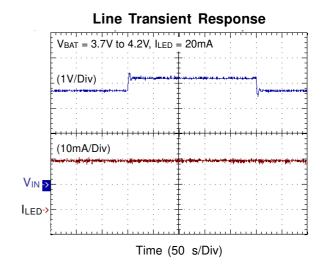












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Applications Information

The RT9301 is a 3-Channel current source driver for RGB LED or white LEDs. The output current can be controlled from 2mA to 50mA by adjusting the setting current from external. It is easy to support a multi-color RGB LED.

Input UVLO

The input operating voltage range of the RT9301 is 2.8V to 5.5V. An input capacitor at the VIN pin could reduce ripple voltage. It is recommended to use a ceramic 1uF or larger capacitance as the input capacitor. This IC provides an under voltage lockout (UVLO) function to prevent it from unstable issue when startup. The UVLO threshold of input falling voltage is set at 2.1V typically with a hysteresis 0.1V.

Output Current Setting

The LED current is setting by the current of ISET pin. The LED current of the three channels (LED1, LED2, LED3) could be set from the ISET (ISET1, ISET2, ISET3) pins individually. The typical application circuit shows as Figure 1.

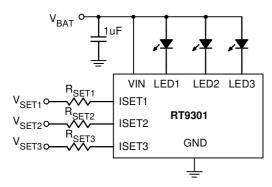


Figure 1. Typical Application Circuit

The LED current can be controlled from an external voltage (V_{SET}) and a resistor (R_{SET}) between VSET and ISET pin. The voltage range of V_{SET} is from 1.3V to 5.5V. The internal reference voltage at ISET pin is 0.9V typically. LED current is set as 800 times the current flowing into ISET pin. Therefore, the LED current can be calculated as the following equation.

ILED1 ~ 3 = 800 x ISET1 ~ 3 = 800 x
$$\frac{V_{SET1} ~ 3 - 0.9V}{R_{SET1} ~ 3}$$

For example, R_{SET1} = 45k Ω and V_{SET1} = 1.8V, the current of LED1 is equal to 16mA.

The LED current of each channel can be controlled from 2mA to 50mA. It is easy to obtain a multi-color output by changing the current of ISET1, ISET2, and ISET3 respectively.

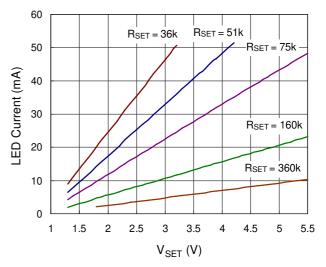


Figure 2. LED Current Setting

Figure 2 shows the characteristics of I_{LED} vs. V_{SET}. If the R_{SET} is selected, the LED current could be controlled from V_{SET}. The voltage of VSET must be higher than 1.3V to enable the LED. For low LED current application, it is recommended to use a higher resistance on RSET (for example: R_{SET} = 360k Ω).

To disable the LED current, the ISET pin should be connected to ground or floating. For one LED or two LEDs application, the unused ISET pin should be connected to GND. In addition, don't short V_{SETx} to ISETx pin.

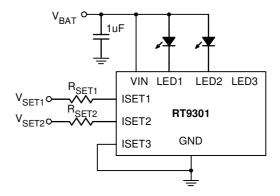


Figure 3. Application Circuit for Two LEDs



GPIO Control

Figure 4 shows an application circuit for backlight with GPIO. The three setting resistors are connected to GPIO. The LED current can be controlled by GPIO directly. The RT9301 provides low dropout voltage and 5% maximum current matching. It also allows dimming control frequency up to 10kHz.

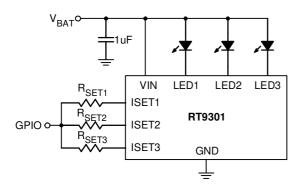


Figure 4. Application Circuit for Backlight with GPIO

The LED current can be set at different value with proper setting resistor. For typical application of GPIO 1.8V/2.8V and LED current 15mA/20mA, the recommended current setting resistors are showed as below table.

Table 1. R_{SET} Value Selection

GPIO	I _{LED}	R _{SET}	Nearest Standard Values for	
(V)	(mA)	(kΩ)	R _{SET} (kΩ)	
1.8	15	48	47.5	
1.0	20	36	36	
2.8	15	101	100	
2.0	20	76	75	

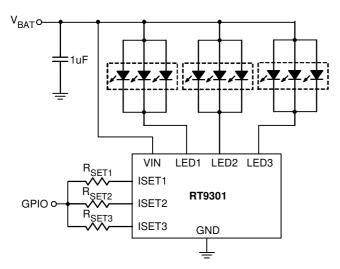


Figure 5. Application Circuit for Keypad Backlight

Figure 5 shows another application circuit for keypad backlight with GPIO. There are 9 LEDs operation in parallel. A battery or a regulated power source drives the LEDs. Each channel supports three LEDs. The LED brightness adjustment can be set with proper setting resistor for each channel and be controlled from GPIO.

Thermal Considerations

For continuous operation, do not exceed absolute maximum operation junction temperature 125°C. The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junction to ambient. The maximum power dissipation can be calculated by following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

Where $T_{J(MAX)}$ is the maximum operation junction temperature 125°C, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance.

For recommended operating conditions specification of RT9301, where $T_{J(MAX)}$ is the maximum junction temperature of the die (125°C) and T_A is the maximum ambient temperature. The junction to ambient thermal resistance θ_{JA} is layout dependent. The thermal resistance θ_{JA} for TSOT-23-8 is 262°C/W, and WDFN-8L 3x3 is 108° C/W on the standard JEDEC 51-3 single-layer thermal test board. The maximum power dissipation at $T_A = 25^{\circ}$ C can be calculated by following formula :

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (262^{\circ}C/W) = 0.382W$ for TSOT-23-8 packages

 $P_{D(MAX)_j} = (125^{\circ}C - 25^{\circ}C) / (108^{\circ}C/W) = 0.926W$ for WDFN-8L3x3 packages

The maximum power dissipation depends on operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance θ_{JA} . For RT9301 packages, the Figure 1 of derating curves allows the designer to see the effect of rising ambient temperature on the maximum power allowed.

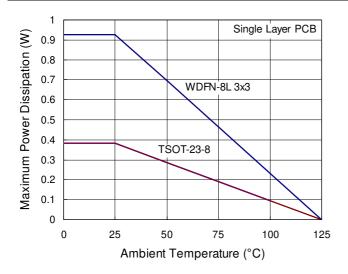
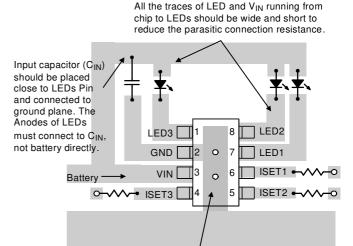


Figure 6. Derating Curves for RT9301 Packages

Layout Consideration

For best performance, careful PCB layout is necessary. Place all peripheral components as close to the IC as possible. A short connection is highly recommended. The following guidelines should be strictly followed when designing a PCB layout for the RT9301.

- 1. All the traces of LED and VIN pin running from chip to LEDs should be wide and short to reduce the parasitic connection resistance.
- 2. Input capacitor (C_{IN}) must be placed close to LEDs and connected to ground plane. The anodes of LEDs must be connected to C_{IN} , not battery directly.
- Current setting resistors R_{SET} should be placed as close to the chip as possible.
- 4. The GND should be connected to a strong ground plane for heat sinking and noise protection.
- 5. The current setting resistors should be placed as close to the IC as possible.

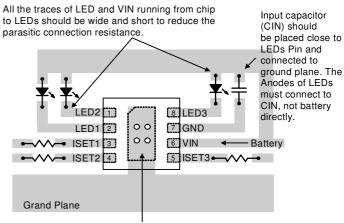


The GND should be connected to a strong ground plane for heat sinking and noise protection.

Figure 7. ecommended PCB Layout of TSOT-23-8

Package

Ground Plane

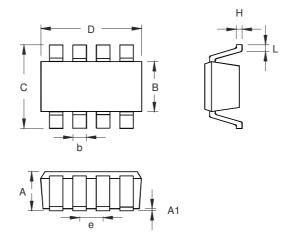


The GND should be connected to a strong ground plane for heat sinking and noise protection.

Figure 8. Recommended PCB Layout of WDFN-8L 3x3 Package



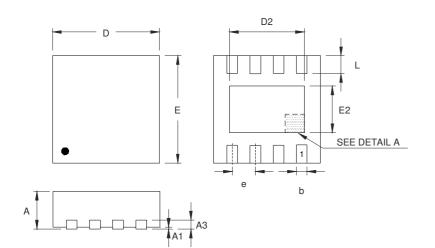
Outline Dimension

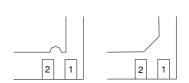


Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.700	1.000	0.028	0.039	
A1	0.000	0.100	0.000	0.004	
В	1.397	1.803	0.055	0.071	
b	0.220	0.380	0.009	0.015	
С	2.591	3.000	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.585	0.715	0.023	0.028	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

TSOT-23-8 Surface Mount Package







DETAIL A

Pin #1 ID and Tie Bar Mark Options

Note: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.200	0.300	0.008	0.012	
D	2.950	3.050	0.116	0.120	
D2	2.100	2.350	0.083	0.093	
Е	2.950	3.050	0.116	0.120	
E2	1.350	1.600	0.053	0.063	
е	0.650		0.026		
L	0.425	0.525	0.017	0.021	

W-Type 8L DFN 3x3 Package

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